

PCN# : P666AAB Issue Date : Jun. 22, 2016

## Information Only Notification

This is to inform you that a change is being made to the following products.

This is a minor change that has no impact on product quality, reliability, electrical or mechanical performance. Affected products will remain fully compliant to all published specifications. Notification is being made for informational purposes only and there is no approval required. Products incorporating this change may be shipped interchangeably with existing unchanged products on or after the issue date of this notification.

Please contact your local Customer Quality Engineer if you have any questions regarding this notification.

## **Implementation of change:**

Description of Change (From) : Drain-Source Diode Characteristics (page 2) Trr (Reverse Recovery Time) limits were 42ns /67ns (Typ / Max) Qrr (Reverse Recovery Charge) limits were 40nC/64nC (Typ / Max)

Description of Change (To) : Drain-Source Diode Characteristics (page 2) Trr (Reverse Recovery Time) limits - 37ns /59ns (Typ / Max) Qrr (Reverse Recovery Charge) limits 27nC/43nC (Typ / Max)

Reason for Change: This is a Datasheet change only.

Updating the Drain-Source Diode paramters due to improved tolerances for test method.



## Affected Product(s):

FDMC86102LZ	FDMC86102LZ_P	FDMC86102LZ_T